STSA851

Low voltage fast-switching NPN power transistor

Features

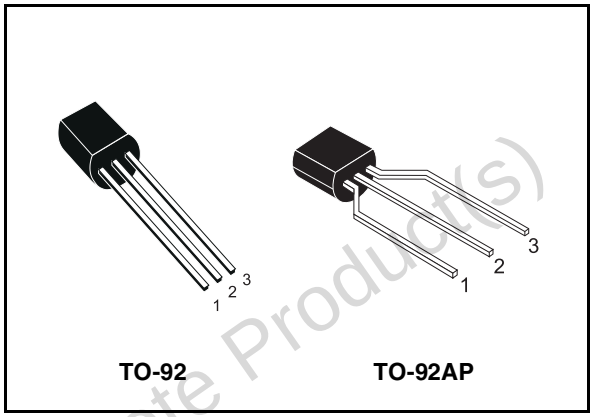
- Very low collector to emitter saturation voltage
- High current gain characteristic
- Fast-switching speed

Applications

- Emergency lighting
- Voltage regulators
- Relay drivers
- High efficiency low voltage switching applications

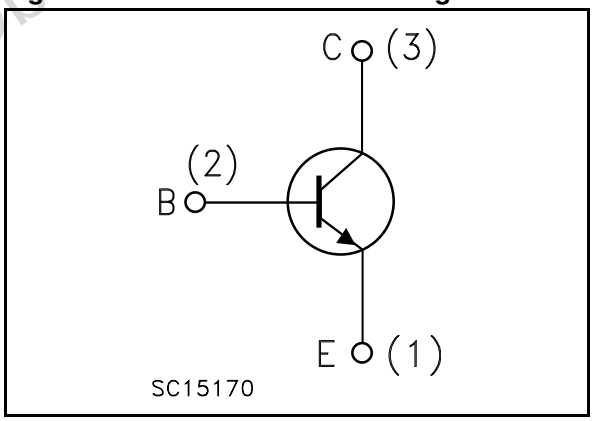
Description

The device is manufactured in NPN planar technology by using a "base island" layout. the resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.



TO-92 TO-92AP

Figure 1. Internal schematic diagram



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Table 1. Device summary

Order code	Marking	Package	Packaging
STSA851	SA851	TO-92	Bulk
STSA851-AP	SA851	TO-92AP	Ammopack

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1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage (I_E = 0)	150	V
V_{CEO}	Collector-emitter voltage (I_B = 0)	60	V
V_{EBO}	Emitter-base voltage (I_C = 0)	7	V
I_C	Collector current	5	A
I_{CM}	Collector peak current (t_P < 5 ms)	20	A
I_B	Base current	1	A
P_{tot}	Total dissipation at T_{amb} = 25 °C	1.1	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter		Value	Unit
$R_{thj\text{-}amb}$	Thermal resistance junction-ambient	max	114	°C/W

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2 Electrical characteristics

(T_{case} = 25 °C unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current (I_E = 0)	V_{CB} = 120 V V_{CB} = 120 V T_C = 100 °C			50 1	nA µA
I_{EBO}	Emitter cut-off current (I_C = 0)	V_{EB} = 7 V			10	nA
$V_{(BR)CBO}$ (1)	Collector-base breakdown Voltage (I_E = 0)	I_C = 100 µA	150			V
$V_{(BR)CEO}$ (1)	Collector-emitter breakdown Voltage (I_B = 0)	I_C = 10 mA	60			V
$V_{(BR)EBO}$ (1)	Emitter-base breakdown Voltage (I_C = 0)	I_E = 100 µA	7			V
$V_{CE(sat)}$ (1)	Collector-emitter saturation voltage	I_C = 100 mA I_B = 5 mA I_C = 1 A I_B = 50 mA I_C = 2 A I_B = 50 mA I_C = 5 A I_B = 200 mA		10 70 140 320	50 120 200 450	mV mV mV mV
$V_{BE(sat)}$ (1)	Base-emitter saturation voltage	I_C = 4 A I_B = 200 mA		1	1.15	V
h_{FE}	DC current gain	I_C = 10 mA V_{CE} = 1 V I_C = 2 A V_{CE} = 1 V I_C = 5 A V_{CE} = 1 V I_C = 10 A V_{CE} = 1 V	150 150 90 30	300 270 140 50	350	
f_T	Transition frequency	V_{CE} = 10 V I_C = 100 mA		130		MHz
C_{CBO}	Collector-base capacitance	V_{CB} = 10 V f = 1 MHz		45		pF
t_{on} t_s t_f	Resistive load Turn-on time Storage time Fall time	I_C = 1 A V_{CC} = 10 V I_{B1} = -I_{B2} = 0.1 A		55 1.35 120		ns µs ns

1. Pulsed duration = 300 µs, duty cycle ≥ 1.5%.

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2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

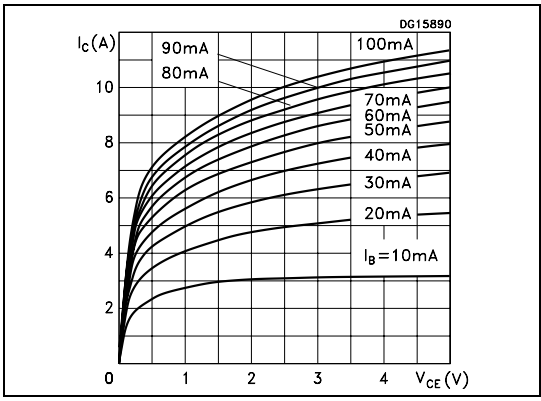


Figure 3. DC current gain

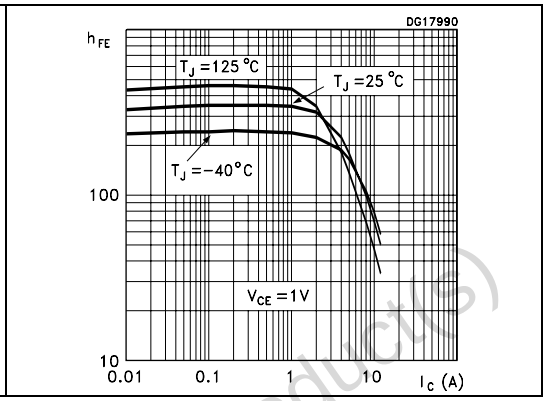


Figure 4. Collector-emitter saturation voltage

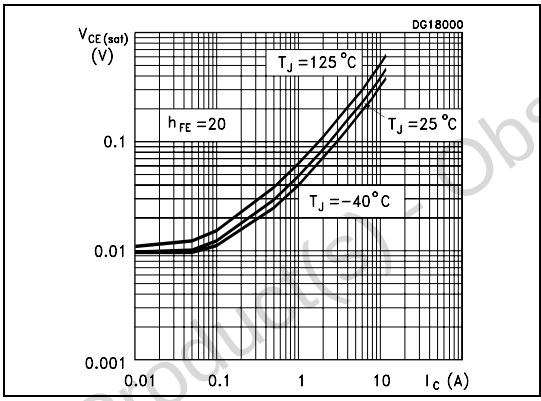


Figure 5. Collector-emitter saturation voltage

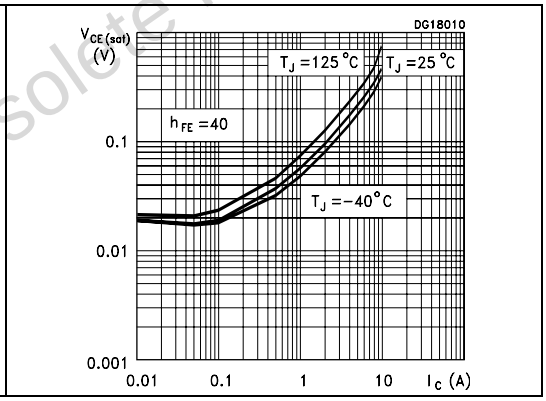


Figure 6. Base-emitter saturation voltage

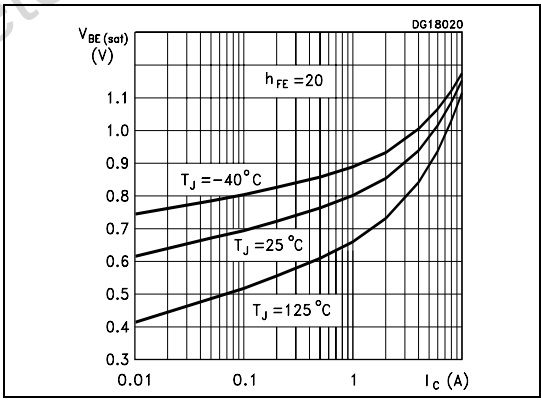
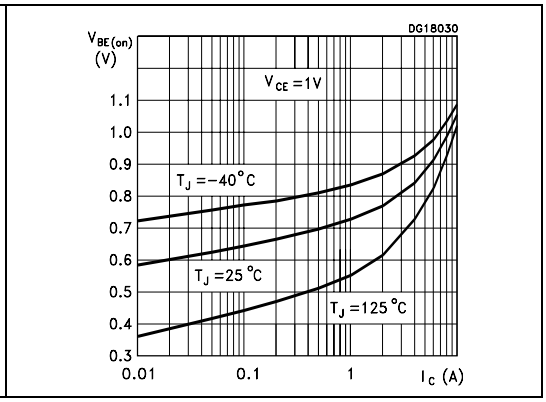


Figure 7. Base-emitter on voltage



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Figure 8. Switching times resistive load

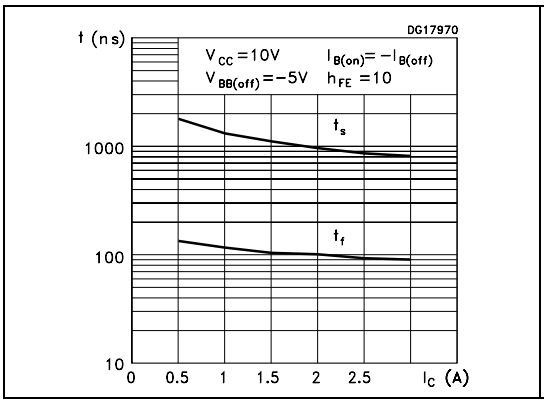


Figure 9. Switching times resistive load

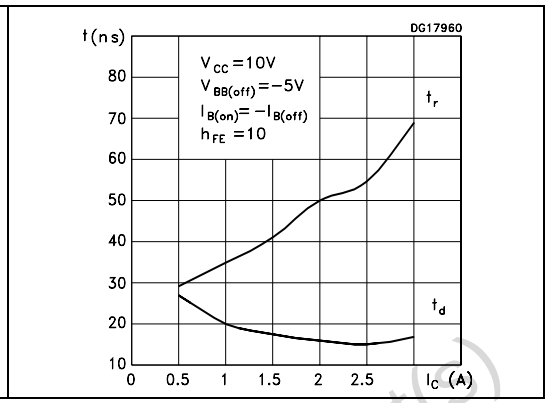
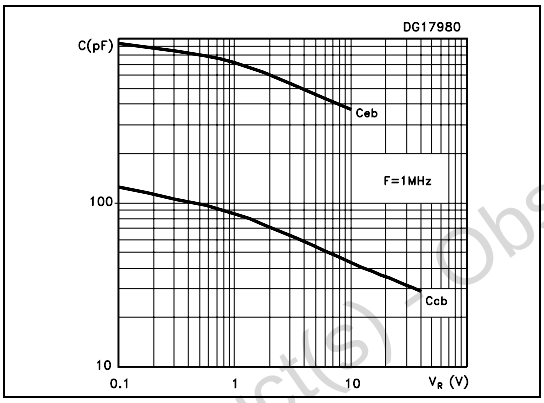
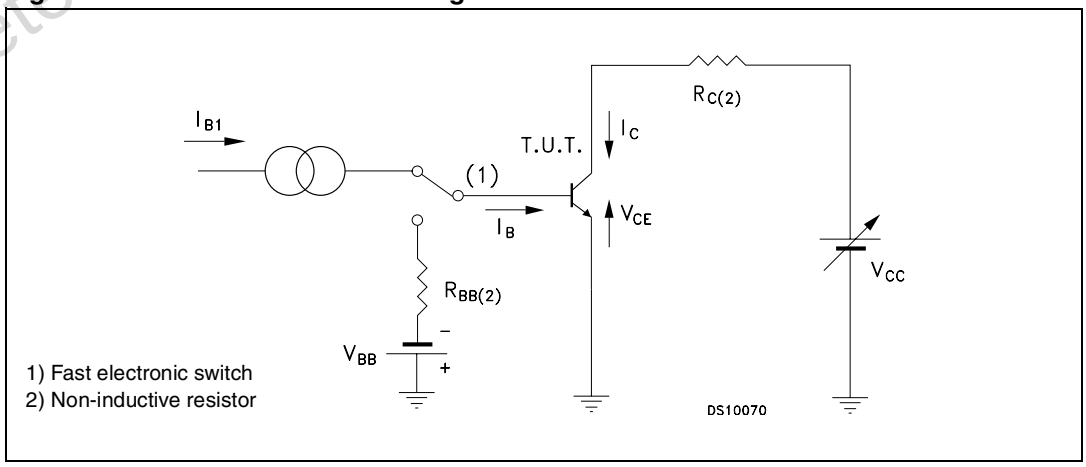


Figure 10. Capacitance



2.2 Test circuit

Figure 11. Resistive load switching test circuit



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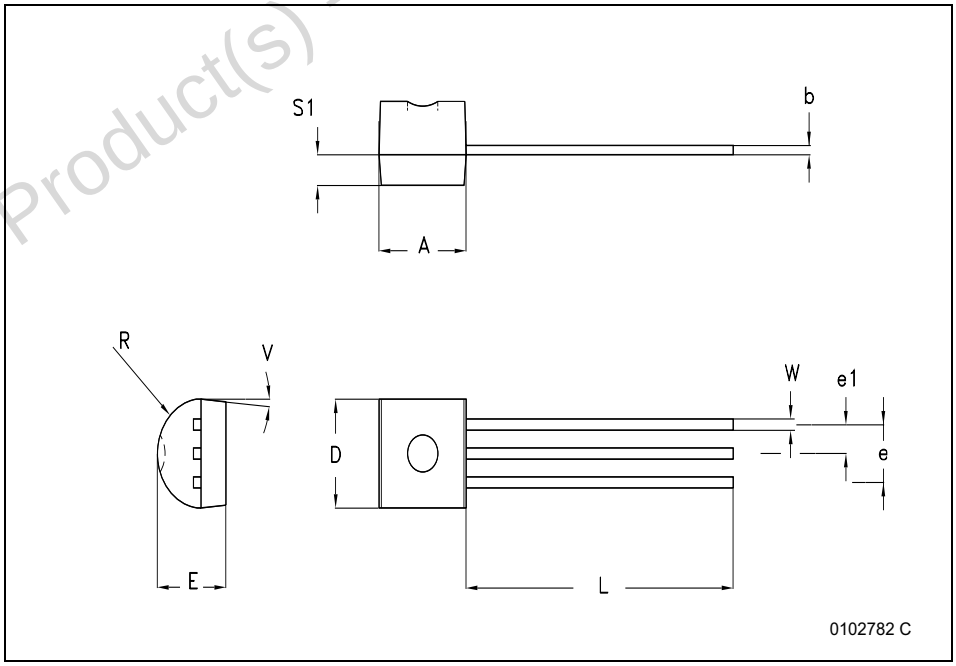
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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TO-92 BULK SHIPMENT MECHANICAL DATA

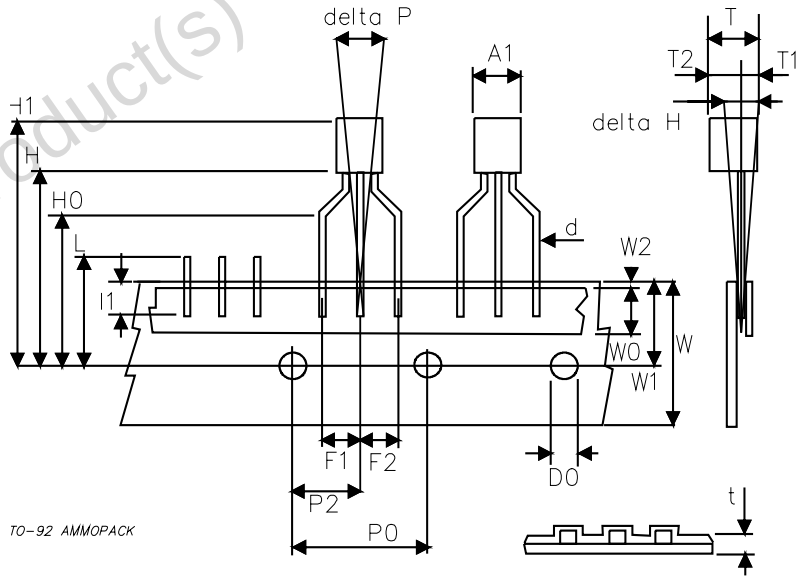
DIM.	mm.		
	MIN.	TYP	MAX.
A	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
e	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5 O	



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TO-92 AMMOPACK SHIPMENT (Suffix"-AP") MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
A1			4.80
T			3.80
T1			1.60
T2			2.30
d			0.48
P0	12.50	12.70	12.90
P2	5.65	6.35	7.05
F1,F2	2.44	2.54	2.94
delta H	-2.00		2.00
W	17.50	18.00	19.00
W0	5.70	6.00	6.30
W1	8.50	9.00	9.25
W2			0.50
H	18.50		20.50
H0	15.50	16.00	16.50
H1			25.00
D0	3.80	4.00	4.20
t			0.90
L			11.00
I1	3.00		
delta P	-1.00		1.00



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4 Revision history

Table 5. Document revision history

Date	Revision	Changes
05-Sep-2003	2	
25-Mar-2008	3	New graphics.

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